

Form PTO-1449		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY. DOCKET NO. 37392	SERIAL NO. 10/521,879		
INFORMATION DISCLOSURE CITATION BY APPLICANT <i>(USE SEVERAL SHEETS IF NECESSARY)</i>				APPLICANT: Fabrice Pardo et al.			
				FILING DATE: January 21, 2005	GROUP ART UNIT:		
U.S. PATENT DOCUMENTS							
Examiner Initial		Document No.	Date	Name	Class	Subclass	Filing Date if Appropriate
	A	5,227,648	07/1993	Woo			
	B	5,663,639	09/1997	Brown et al.			
	C						
	D						
	E						
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		Document No.	Date	Country	Class	Subclass	Translation
	F	0 651 448 A1	03/1995	European			Corresponds to U.S. Patent No.: 5,512,763
	G	2 803 950	07/2001	France			Corresponds to U.S. Publication No.: 2003/010979
	H						
OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, Etc.)							
	I	Katsumi Kishino et al., "Resonant Cavity-Enhanced (RCE) Photodetectors, August 8, 2001, pages 2025 - 2034,					
	J	Wolfgang Kowalsky et al., "High Bandwidth Metal-Semiconductor-Metal Photodiodes with Integrated Fabry-Perot Resonator for WDM Receivers", August 1992, Pages 214 - 216					
	K	A. Strittmatter et al., "High-Speed, High Efficiency Resonant-Cavity Enhanced InGaAs MSM Photodetectors", Pages 1231- 1232 20 June 1996					
	L	A. Strittmatter et al., "High-Frequency , Long-Wavelength Resonant-Cavity-Enhanced InGaAs MSM Photodetectors", September 15, 1996, Pages 145 - 148					
Examiner: /John Ingham/					Date Considered 08/14/2009		
*Examiner: Initial if reference considered, regardless of whether citation is in conformance with MPEP 609; Draw line through citation if not in conformance <u>and</u> not considered. Include copy of this form with next communication to applicant.							